## Terra-Pixel APS for CALICE

Progress meeting 10<sup>th</sup> Nov 2005 Jamie Crooks, Microelectronics/RAL

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# Stitching

#### 4 x 6.2cm chips

1 x 13cm chip



#### Test structures?



• Full 13cm readout length Smaller arrays for tests

### Need to fully dice?



- 150um scribe lanes, could remain uncut...
- Could cut a 13x13cm area from the wafer containing an array of chips with 150um spacings?
- Yield?
- Bonding / alignment complications?
- •



108 Chips @ 5.6cm = 22 wafers



#### PCB concerns

~100 LVDS pairs to FPGA Power planes, local decoupling Differential clock and control signals? Well designed clock distribution! Synchronisation? PLLs?

Serial chain of all chips onboard for setup programming?Optical links along PCB?Less control signals the better!



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## Data Access times

- Per physics event
  - 2000 hits per layer
  - If these were all on a single chip...
  - @6.6Mhz, reading 2 values per pixel, takes
    600uS to read those 2k pixels
  - How many "physics events" per train?

# Power Consumption

- Example: Single clock line driven to every pixel...
  - Calculation for a 1mm square, 50um pixels
  - 0.22pF estimated line capacitance (per col)
  - Clock rate 6.6Mhz (150ns repetition) at 3.3V
  - 319uW per square mm
  - Allowing 2% duty cycle, à 6.4uW per sq mm

<sup>(</sup>for one global signal to 400 pixels)

### Perpendicular memory cells?



Parallel write Serial read

- + less sense amps
- + serial out consistent with link to FPGA
- + Din/out perpendicular
- Need 16 1-bit shift register cells in every cell instead of 1
- Different column lengths depending on hits

#### Perpendicular memory cells 2?



Parallel read Serial write

Timing code is shifted along through pixels Or generated from single bit shift registers in neighbour pixels Reduced power load to distribute timing code Added complexity/scrambled data Would require some set-up time before pulse train

## "Current Focus"

- Register selection for write <u>and</u> read access
- Suitable low-power clocked comparator with adjustable threshold/offset
- Analog circuits in the pixel
  - Continuous reset mode
  - How to "add" multiple pixel values
- DRAM Cells
  - Stacked capacitors are possible
  - Simulate and compare lifetime with "physics events" statistics to establish suitability of dynamic storage
  - Sample layouts to indicate cell size